

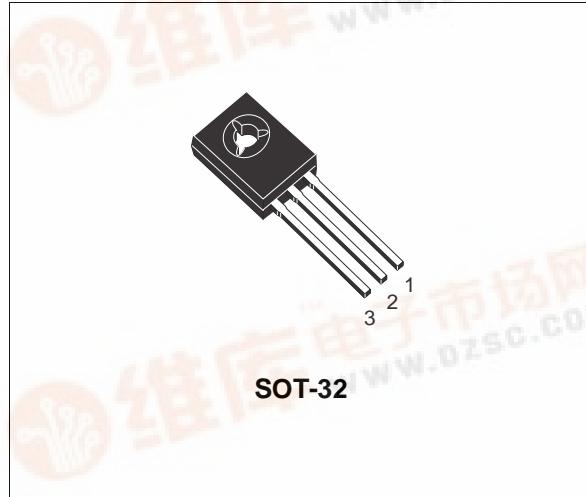
**MJE521**

SILICON NPN TRANSISTOR

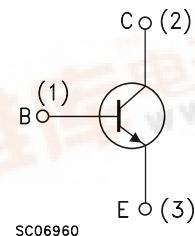
■ SGS-THOMSON PREFERRED SALESTYPE

DESCRIPTION

The MJE521 is a silicon epitaxial-base NPN transistor in Jedec SOT-32 plastic package, intended for use in 5 to 20W audio amplifiers, general purpose amplifier and switching circuits.

**SOT-32**

INTERNAL SCHEMATIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage ($I_E = 0$)	40	V
V_{CEO}	Collector-Emitter Voltage ($I_B = 0$)	40	V
V_{EBO}	Emitter-Base Voltage ($I_C = 0$)	4	V
I_C	Collector Current	4	A
I_{CM}	Collector Peak Current	8	A
I_B	Base Current	2	A
P_{tot}	Total Dissipation at $T_c \leq 25^\circ\text{C}$	40	W
T_{stg}	Storage Temperature	-65 to +150	$^\circ\text{C}$
T_j	Max. Operating Junction Temperature	150	$^\circ\text{C}$

MJE521

THERMAL DATA

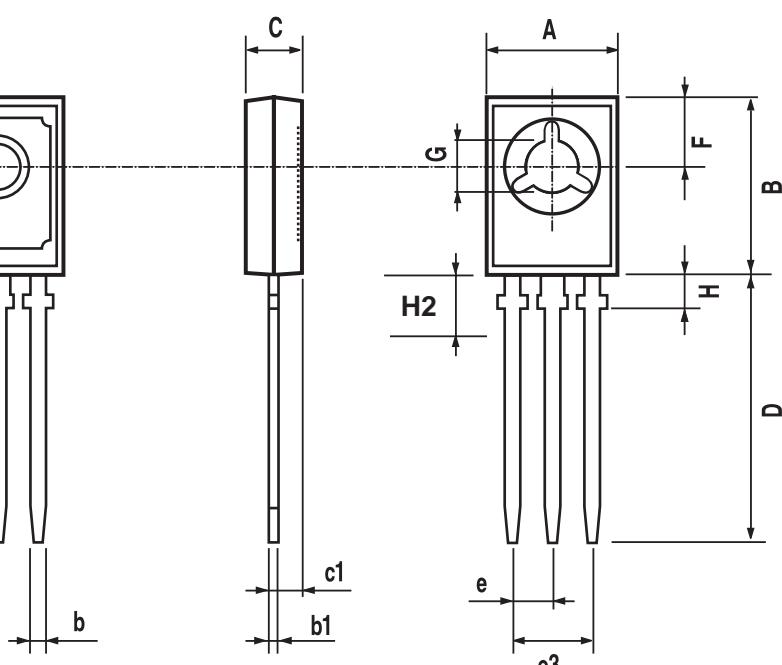
R _{thj-amb}	Thermal Resistance Junction-ambient	Max	3.12	°C/W
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ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I _{CBO}	Collector Cut-off Current (I _E = 0)	V _{CB} = 40 V			100	µA
I _{EBO}	Emitter Cut-off Current (I _C = 0)	V _{EB} = 4 V			100	µA
V _{CEO(sus)*}	Collector-Emitter Sustaining Voltage (I _B = 0)	I _C = 0.1 A	40			V
h _{FE}	DC Current Gain	I _C = 1 A V _{CE} = 1 V	40			

* Pulsed: Pulse duration = 300µs, duty cycle ≤ 1.5%

SOT-32 (TO-126) MECHANICAL DATA						
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	7.4		7.8	0.291		0.307
B	10.5		10.8	0.413		0.445
b	0.7		0.9	0.028		0.035
b1	0.49		0.75	0.019		0.030
C	2.4		2.7	0.040		0.106
c1	1.0		1.3	0.039		0.050
D	15.4		16.0	0.606		0.629
e		2.2			0.087	
e3	4.15		4.65	0.163		0.183
F		3.8			0.150	
G	3		3.2	0.118		0.126
H			2.54			0.100
H2		2.15			0.084	



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